

## SEMIPONT ${ }^{\circledR} 4$

Power Bridge Rectifiers

SKD 160

## Features

- Robust plastic case with screw terminals
- Large, isolated base plate
- Blocking voltage up to 1800 V
- High surge currents
- Three phase brige rectifier
- Easy chassis mounting
- UL recognized, file no. E 63532


## Typical Applications

- Three phase rectifiers for power supplies
- Input rectifiers for variable frequency drives
- Rectifiers for DC motor field supplies
- Battery charger rectifiers

1) Available in limited quantities
2) Mounted on a painted metal sheet of min. $250 \times 250 \times 1 \mathrm{~mm}$;
$R_{\text {th(c-a) }}=1,8 \mathrm{~K} / \mathrm{W}$

SKD


| $\mathrm{V}_{\text {RSM }}$ | $\mathrm{V}_{\text {RRM }}, \mathrm{V}_{\mathrm{DRM}}$ | $\mathrm{I}_{\mathrm{D}}=160 \mathrm{~A}$ (full conduction) |
| :---: | :---: | :---: |
| V | V | $\left(\mathrm{T}_{\mathrm{C}}=100^{\circ} \mathrm{C}\right)$ |
| 400 | 400 | SKD 160/04 |
| 800 | 800 | SKD 160/08 |
| 1200 | 1200 | SKD 160/12 |
| 1400 | 1400 | SKD 160/14 |
| 1600 | 1600 | SKD 160/16 |
| 1800 | 1800 | SKD 160/18 ${ }^{1)}$ |


| Symbol | Conditions | Values | Units |
| :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{D}}$ | $\mathrm{T}_{\mathrm{c}}=85^{\circ} \mathrm{C}$ | 205 | A |
|  | $\mathrm{T}_{\mathrm{a}}=45^{\circ} \mathrm{C}$; chassis ${ }^{2}{ }^{2}$ | 30 | A |
|  | $\mathrm{T}_{\mathrm{a}}=45^{\circ} \mathrm{C} ; \mathrm{P} 1 / 200$ | 75 | A |
|  | $\mathrm{T}_{\mathrm{a}}=35^{\circ} \mathrm{C} ;$ P1/120F | 145 | A |
|  | $\mathrm{T}_{\mathrm{a}}=35^{\circ} \mathrm{C} ; \mathrm{P} 3 / 120 \mathrm{~F}$ | 146 | A |
| $\mathrm{I}_{\text {FSM }}$ | $\mathrm{T}_{\mathrm{vj}}=25^{\circ} \mathrm{C} ; 10 \mathrm{~ms}$ | 1800 | A |
|  | $\mathrm{T}_{\mathrm{vj}}=150^{\circ} \mathrm{C} ; 10 \mathrm{~ms}$ | 1500 | A |
| i2t | $\mathrm{T}_{\mathrm{vj}}=25^{\circ} \mathrm{C} ; 8,3 \ldots 10 \mathrm{~ms}$ | 16200 | $A^{2} \mathrm{~S}$ |
|  | $\mathrm{T}_{\mathrm{vj}}=150^{\circ} \mathrm{C} ; 8,3 \ldots 10 \mathrm{~ms}$ | 11200 | $\mathrm{A}^{2} \mathrm{~S}$ |
| $V_{F}$ | $\mathrm{T}_{\mathrm{vj}}=25^{\circ} \mathrm{C} ; \mathrm{I}_{\mathrm{F}}=300 \mathrm{~A}$ | max. 1,65 | V |
| $V_{\text {(TO) }}$ | $\mathrm{T}_{\mathrm{vj}}=150^{\circ} \mathrm{C}$ | max. 0,85 | V |
| $\mathrm{r}_{\mathrm{T}}$ | $\mathrm{T}_{\mathrm{vj}}=150^{\circ} \mathrm{C}$ | max. 3 | $\mathrm{m} \Omega$ |
| $\mathrm{I}_{\text {RD }}$ | $\mathrm{T}_{\mathrm{vj}}=25^{\circ} \mathrm{C} ; \mathrm{V}_{\mathrm{DD}}=\mathrm{V}_{\mathrm{DRM}} ; \mathrm{V}_{\mathrm{RD}}=\mathrm{V}_{\mathrm{RRM}}$ | max. 0,5 | mA |
|  | $\mathrm{T}_{\mathrm{vj}}=150^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{RD}}=\mathrm{V}_{\mathrm{RRM}}$ | 6 | mA |
| $\mathrm{R}_{\mathrm{th}(\mathrm{j} \mathrm{c})}$ | per diode | 0,65 | K/W |
|  | total | 0,11 | K/W |
| $\mathrm{R}_{\mathrm{th}(\mathrm{c}-\mathrm{s})}$ | total | 0,03 | K/W |
| $\mathrm{T}_{\mathrm{vj}}$ |  | $-40 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-40 \ldots+125$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{V}_{\text {isol }}$ | a. c. 50 Hz ; r.m.s.; $1 \mathrm{~s} / 1 \mathrm{~min}$. | 3600 ( 3000 ) | V |
| $\mathrm{M}_{\text {s }}$ | to heatsink | $5 \pm 15$ \% | Nm |
| $M_{t}$ | to terminals | $5 \pm 15$ \% | Nm |
| m |  | 270 | g |
| Case |  | G 37 |  |





Fig. 12 Transient thermal impedance vs. time




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